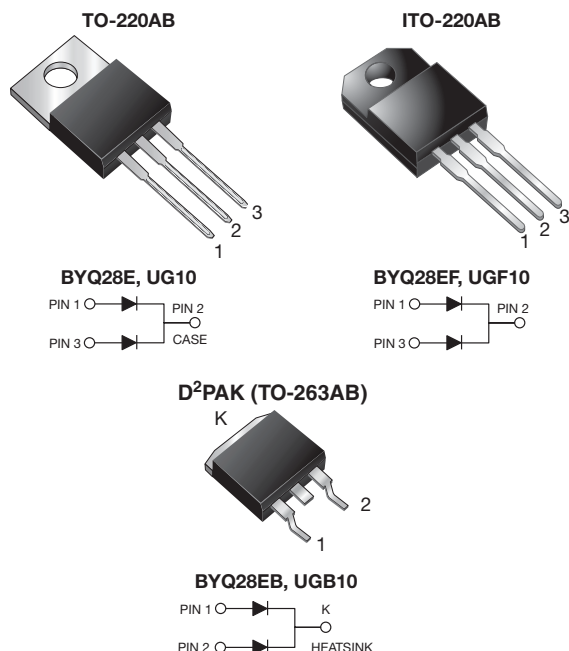


Dual Common Cathode Ultrafast Rectifier



DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	100 V to 200 V
I_{FSM}	55 A
t_{rr}	25 ns
V_F	0.895 V
T_J max.	150 °C
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)
Circuit configuration	Common cathode

FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery times
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C for D²PAK (TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
- Automotive ordering code: base P/NHE3 (for ITO-220AB and D²PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB)
Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UG10BCT	UG10CCT	UG10DCT	UNIT
		BYQ28E-100	BYQ28E-150	BYQ28E-200	
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V
Working peak reverse voltage	V _{RWM}	100	150	200	V
Maximum DC blocking voltage	V _{DC}	100	150	200	V
Maximum average forward rectified current at T _C = 100 °C — total device per diode	I _{F(AV)}	10			A
		5.0			
Peak forward surge current 8.3 ms single half sine-wave	I _{FSM}	55			A
Non-repetitive peak reverse current per diode at t _p = 100 μs	I _{RSM}	0.2			A
Electrostatic discharge capacitor voltage, human body model: C = 250 pF, R = 1.5 kΩ	V _C	8			kV
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150			°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V



ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage per diode	$I_F = 10\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_F^{(1)}$	1.25	V
	$I_F = 5\text{ A}$	$T_J = 150\text{ }^{\circ}\text{C}$		1.10	
		$T_J = 150\text{ }^{\circ}\text{C}$		0.895	
Maximum reverse current per diode at working peak reverse voltage		$T_J = 25\text{ }^{\circ}\text{C}$	I_R	10	μA
		$T_J = 100\text{ }^{\circ}\text{C}$		200	
Maximum reverse recovery time per diode	$I_F = 1.0\text{ A}$, $dI/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $I_{rr} = 0.1\text{ I}_{RM}$		t_{rr}	25	ns
Maximum reverse recovery time per diode	$I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{rr} = 0.25\text{ A}$		t_{rr}	20	ns
Maximum stored charge per diode	$I_F = 2\text{ A}$, $dI/dt = 20\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $I_{rr} = 0.1\text{ I}_{RM}$		Q_{rr}	9	nC

Note
⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	UG10	UGF10	UGB10	UNIT
		BYQ28E	BYQ28EF	BYQ28EB	
Typical thermal resistance per diode, junction to ambient	$R_{\theta JA}$	50	55	50	$^{\circ}\text{C}/\text{W}$
Typical thermal resistance per diode, junction to case	$R_{\theta JC}$	4.5	6.7	4.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYQ28E-200-E3/45	1.80	45	50/tube	Tube
ITO-220AB	BYQ28EF-200-E3/45	1.95	45	50/tube	Tube
D ² PAK (TO-263AB)	BYQ28EB-200-E3/45	1.77	45	50/tube	Tube
D ² PAK (TO-263AB)	BYQ28EB-200-E3/81	1.77	81	800/reel	Tape and reel
ITO-220AB	BYQ28EF-200HE3_A/P ⁽¹⁾	1.95	P	50/tube	Tube
D ² PAK (TO-263AB)	BYQ28EB-200HE3_A/P ⁽¹⁾	1.95	P	50/tube	Tube
D ² PAK (TO-263AB)	BYQ28EB-200HE3_A/I ⁽¹⁾	1.95	I	800/reel	Tape and reel

Note
⁽²⁾ AEC-Q101 qualified, available in ITO-220AB and D²PAK (TO-263AB) package



RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

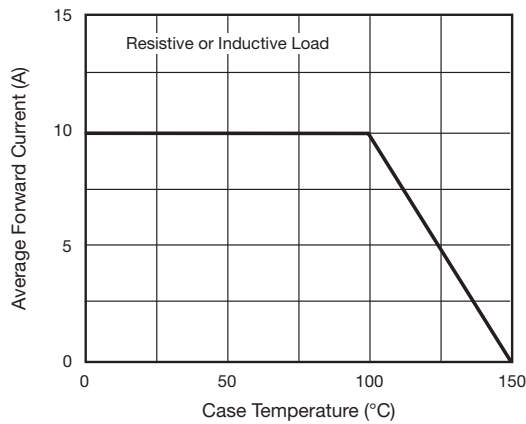


Fig. 1 - Forward Current Derating Curve

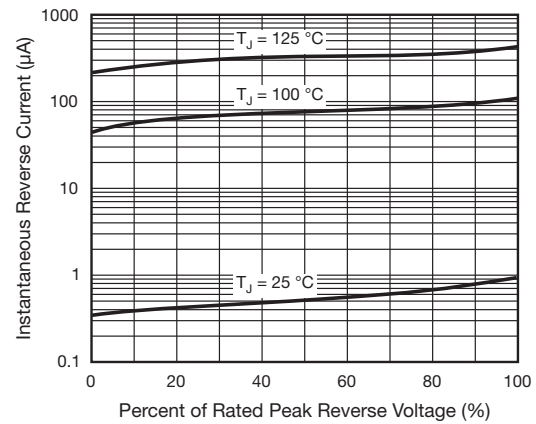


Fig. 4 - Typical Reverse Characteristics Per Diode

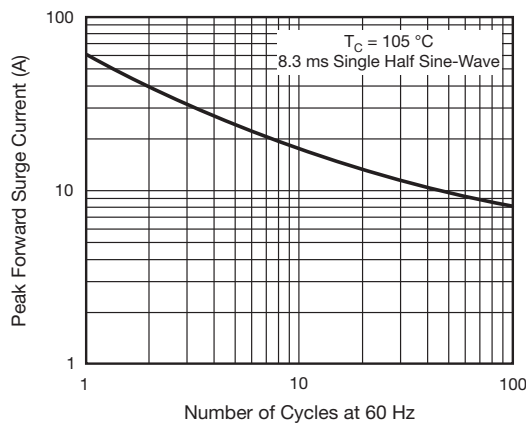


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

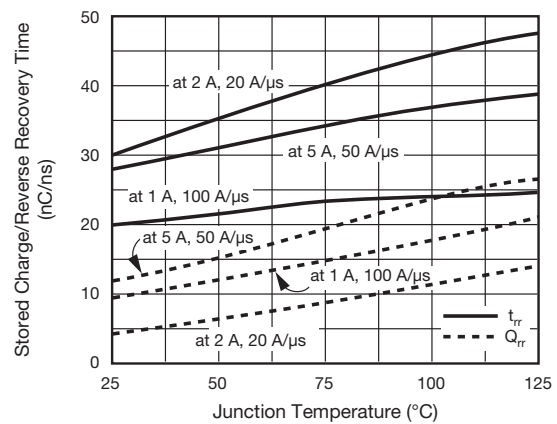


Fig. 5 - Reverse Switching Characteristics Per Diode

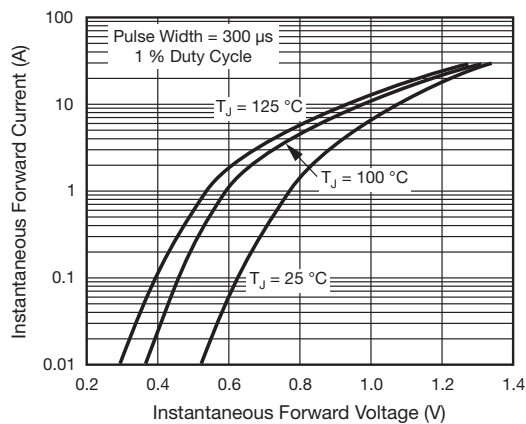


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

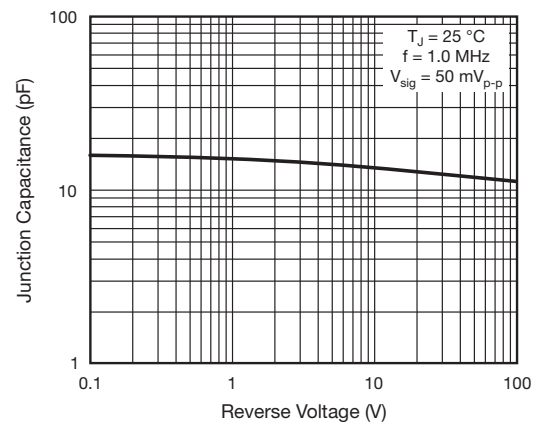
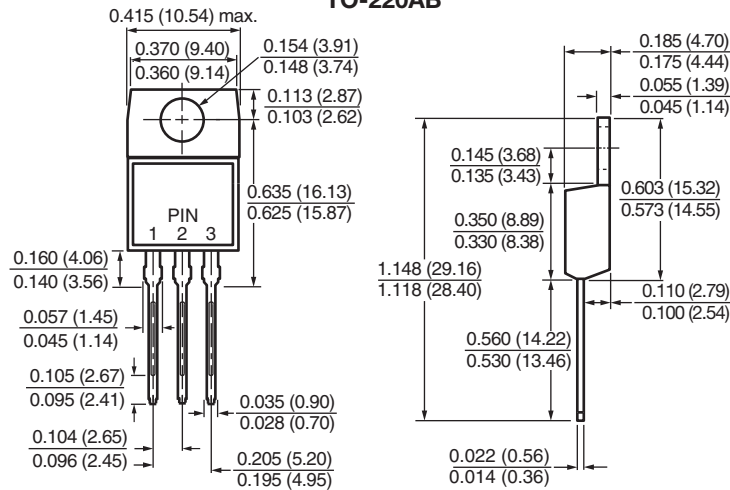


Fig. 6 - Typical Junction Capacitance Per Diode

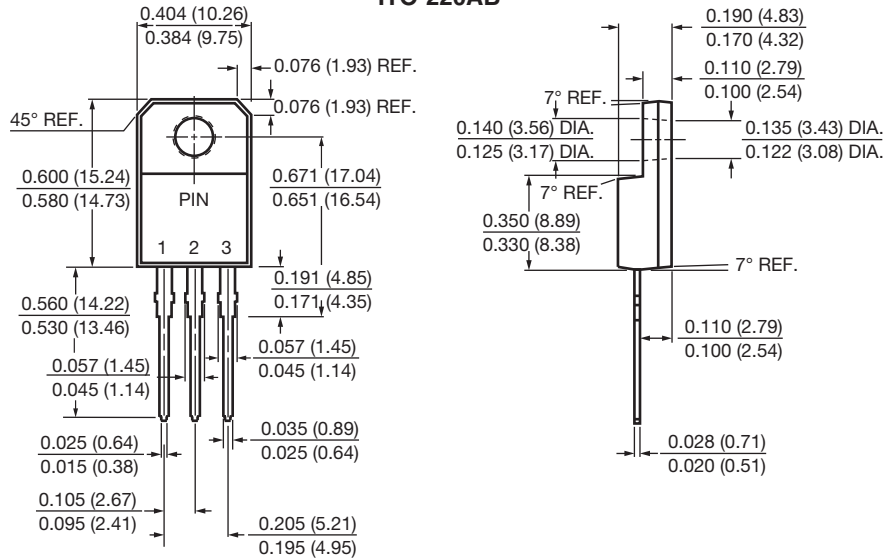


PACKAGE OUTLINE DIMENSION in inches (millimeters)

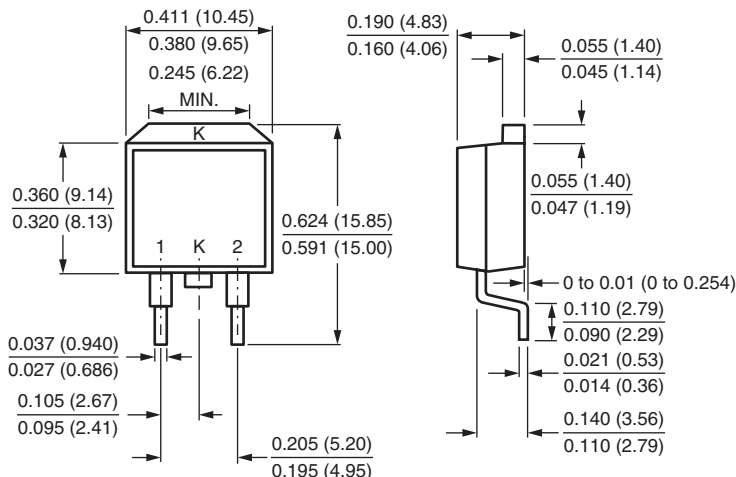
TO-220AB



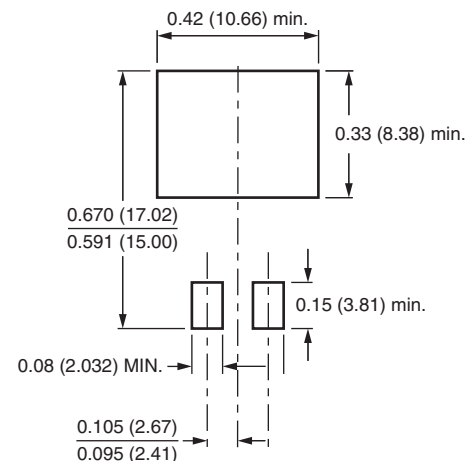
ITO-220AB



D²PAK (TO-263AB)



Mounting Pad Layout





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